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Understanding [Embedded - Microprocessors](#)

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of [Embedded - Microprocessors](#)

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Active
Core Processor	ARM® Cortex®-A7
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	528MHz
Co-Processors/DSP	Multimedia; NEON™ MPE
RAM Controllers	LPDDR2, DDR3, DDR3L
Graphics Acceleration	No
Display & Interface Controllers	Electrophoretic, LCD
Ethernet	10/100Mbps (1)
SATA	-
USB	USB 2.0 OTG + PHY (2)
Voltage - I/O	1.8V, 2.8V, 3.3V
Operating Temperature	-40°C ~ 105°C (TJ)
Security Features	A-HAB, ARM TZ, CSU, SJC, SNVS
Package / Case	272-LFBGA
Supplier Device Package	272-MAPBGA (9x9)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcimx6y1cvk05ab

i.MX 6ULL Introduction

The i.MX 6ULL processors are specifically useful for applications such as:

- Telematics
- Audio playback
- Connected devices
- IoT Gateway
- Access control panels
- Human Machine Interfaces (HMI)
- Portable medical and health care
- IP phones
- Smart appliances
- eReaders

The features of the i.MX 6ULL processors include:

- Single-core Arm Cortex-A7—The single core A7 provides a cost-effective and power-efficient solution.
- Multilevel memory system—The multilevel memory system of processor is based on the L1 instruction and data caches, L2 cache, and internal and external memory. The processor supports many types of external memory devices, including DDR3, low voltage DDR3, LPDDR2, NOR Flash, NAND Flash (MLC and SLC), OneNAND™, Quad SPI, and managed NAND, including eMMC up to rev 4.4/4.41/4.5.
- Smart speed technology—Power management implemented throughout the IC that enables multimedia features and peripherals to consume minimum power in both active and various low power modes.
- Dynamic voltage and frequency scaling—The power efficiency of devices by scaling the voltage and frequency to optimize performance.
- Multimedia powerhouse—The multimedia performance of processor is enhanced by a multilevel cache system, NEON™ MPE (Media Processor Engine) co-processor, a programmable smart DMA (SDMA) controller, an asynchronous audio sample rate converter, an Electrophoretic Display (EPD) controller, and a Pixel processing pipeline (PXP) to support 2D image processing, including color-space conversion, scaling, alpha-blending, and rotation.
- 2x Ethernet interfaces—2x 10/100 Mbps Ethernet controllers.
- Human-machine interface—Each processor supports one digital parallel display interface.
- Interface flexibility—Each processor supports connections to a variety of interfaces: two high-speed USB on-the-go with PHY, multiple expansion card ports (high-speed MMC/SDIO host and other), two 12-bit ADC modules with up to 10 total input channels and two CAN ports.
- Advanced security—The processors deliver hardware-enabled security features that enable secure e-commerce, digital rights management (DRM), information encryption, secure boot, AES-128 encryption, SHA-1, SHA-256 HW acceleration engine, and secure software downloads. The security features are discussed in the *i.MX 6ULL Security Reference Manual* (IMX6ULLSRM).

3 Modules List

The i.MX 6ULL processors contain a variety of digital and analog modules. [Table 2](#) describes these modules in alphabetical order.

Table 2. i.MX 6ULL Modules List

Block Mnemonic	Block Name	Subsystem	Brief Description
ADC1 ADC2	Analog to Digital Converter	—	The ADC is a 12-bit general purpose analog to digital converter.
Arm	Arm Platform	Arm	The Arm Core Platform includes 1x Cortex-A7 core. It also includes associated sub-blocks, such as the Level 2 Cache Controller, SCU (Snoop Control Unit), GIC (General Interrupt Controller), private timers, watchdog, and CoreSight debug modules.
ASRC	Asynchronous Sample Rate Converter	Multimedia Peripherals	The Asynchronous Sample Rate Converter (ASRC) converts the sampling rate of a signal associated to an input clock into a signal associated to a different output clock. The ASRC supports concurrent sample rate conversion of up to 10 channels of about -120dB THD+N. The sample rate conversion of each channel is associated to a pair of incoming and outgoing sampling rates. The ASRC supports up to three sampling rate pairs.
BCH	Binary-BCH ECC Processor	System Control Peripherals	The BCH module provides up to 40-bit ECC encryption/decryption for NAND Flash controller (GPMI)
CCM GPC SRC	Clock Control Module, General Power Controller, System Reset Controller	Clocks, Resets, and Power Control	These modules are responsible for clock and reset distribution in the system, and also for the system power management.
CSI	Parallel CSI	Multimedia Peripherals	The CSI IP provides parallel CSI standard camera interface port. The CSI parallel data ports are up to 24 bits. It is designed to support 24-bit RGB888/YUV444, CCIR656 video interface, 8-bit YCbCr, YUV or RGB, and 8-bit/10-bit/16-bit Bayer data input.
CSU	Central Security Unit	Security	The Central Security Unit (CSU) is responsible for setting comprehensive security policy within the i.MX 6ULL platform.
DAP	Debug Access Port	System Control Peripherals	The DAP provides real-time access for the debugger without halting the core to: <ul style="list-style-type: none"> • System memory and peripheral registers • All debug configuration registers The DAP also provides debugger access to JTAG scan chains. The DAP module is internal to the Cortex-A7 Core Platform.

The typical values shown in [Table 12](#) are required for use with NXP BSPs to ensure precise time keeping and USB operation. For RTC_XTALI operation, two clock sources are available.

- On-chip 40 kHz ring oscillator—this clock source has the following characteristics:
 - Approximately 25 μ A more Idd than crystal oscillator
 - Approximately $\pm 50\%$ tolerance
 - No external component required
 - Starts up quicker than 32 kHz crystal oscillator
- External crystal oscillator with on-chip support circuit:
 - At power up, ring oscillator is utilized. After crystal oscillator is stable, the clock circuit switches over to the crystal oscillator automatically.
 - Higher accuracy than ring oscillator
 - If no external crystal is present, then the ring oscillator is utilized

The decision of choosing a clock source should be taken based on real-time clock use and precision time-out.

4.1.5 Maximum Supply Currents

The data shown in [Table 13](#) represent a use case designed specifically to show the maximum current consumption possible. All cores are running at the defined maximum frequency and are limited to L1 cache accesses only to ensure no pipeline stalls. Although a valid condition, it would have a very limited practical use case, if at all, and be limited to an extremely low duty cycle unless the intention was to specifically show the worst case power consumption.

See the i.MX 6ULL Power Consumption Measurement Application Note (AN4581) for more details on typical power consumption under various use case definitions.

Table 13. Maximum Supply Currents

Power Line	Conditions	Max Current	Unit
VDD_SOC_IN	792 MHz Arm clock based on Dhrystone test	500	mA
VDD_HIGH_IN	—	125 ¹	mA
VDD_SNVS_IN	—	500 ²	μ A
USB_OTG1_VBUS USB_OTG2_VBUS	—	50 ³	mA
VDDA_ADC_3P3	100 Ohm maximum loading for touch panel	35	mA
Primary Interface (IO) Supplies			
NVCC_DRAM	—	(See ⁴)	—
NVCC_DRAM_2P5	—	50	mA
NVCC_GPIO	N=16	Use maximum IO Equation ⁵	—

Table 31. DDR I/O LPDDR2 Mode AC Parameters¹ (continued)

Parameter	Symbol	Test Condition	Min	Max	Unit
Single output slew rate, measured between Vol (ac) and Voh (ac)	tsr	50 Ω to Vref. 5 pF load. Drive impedance = 40 Ω ± 30%	1.5	3.5	V/ns
		50 Ω to Vref. 5pF load.Drive impedance = 60 Ω ± 30%	1	2.5	
Skew between pad rise/fall asymmetry + skew caused by SSN	t _{SKD}	clk = 400 MHz	—	0.1	ns

¹ Note that the JEDEC LPDDR2 specification (JESD209_2B) supersedes any specification in this document.

² Vid(ac) specifies the input differential voltage | Vtr - Vcp | required for switching, where Vtr is the “true” input signal and Vcp is the “complementary” input signal. The Minimum value is equal to Vih(ac) - Vil(ac).

³ The typical value of Vix(ac) is expected to be about 0.5 x OVDD. and Vix(ac) is expected to track variation of OVDD. Vix(ac) indicates the voltage at which differential input signal must cross.

Table 32 shows the AC parameters for DDR I/O operating in DDR3/DDR3L mode.

Table 32. DDR I/O DDR3/DDR3L Mode AC Parameters¹

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
AC input logic high	Vih(ac)	—	Vref + 0.175	—	OVDD	V
AC input logic low	Vil(ac)	—	0	—	Vref - 0.175	V
AC differential input voltage ²	Vid(ac)	—	0.35	—	—	V
Input AC differential cross point voltage ³	Vix(ac)	Relative to Vref	Vref - 0.15	—	Vref + 0.15	V
Over/undershoot peak	Vpeak	—	—	—	0.4	V
Over/undershoot area (above OVDD or below OVSS)	Varea	400 MHz	—	—	0.5	V-ns
Single output slew rate, measured between Vol (ac) and Voh (ac)	tsr	Driver impedance = 34 Ω	2.5	—	5	V/ns
Skew between pad rise/fall asymmetry + skew caused by SSN	t _{SKD}	clk = 400 MHz	—	—	0.1	ns

¹ Note that the JEDEC JESD79_3C specification supersedes any specification in this document.

² Vid(ac) specifies the input differential voltage | Vtr-Vcp | required for switching, where Vtr is the “true” input signal and Vcp is the “complementary” input signal. The Minimum value is equal to Vih(ac) - Vil(ac).

³ The typical value of Vix(ac) is expected to be about 0.5 x OVDD. and Vix(ac) is expected to track variation of OVDD. Vix(ac) indicates the voltage at which differential input signal must cross.

4.8 Output Buffer Impedance Parameters

This section defines the I/O impedance parameters of the i.MX 6ULL processors for the following I/O types:

- Single Voltage General Purpose I/O (GPIO)

Electrical Characteristics

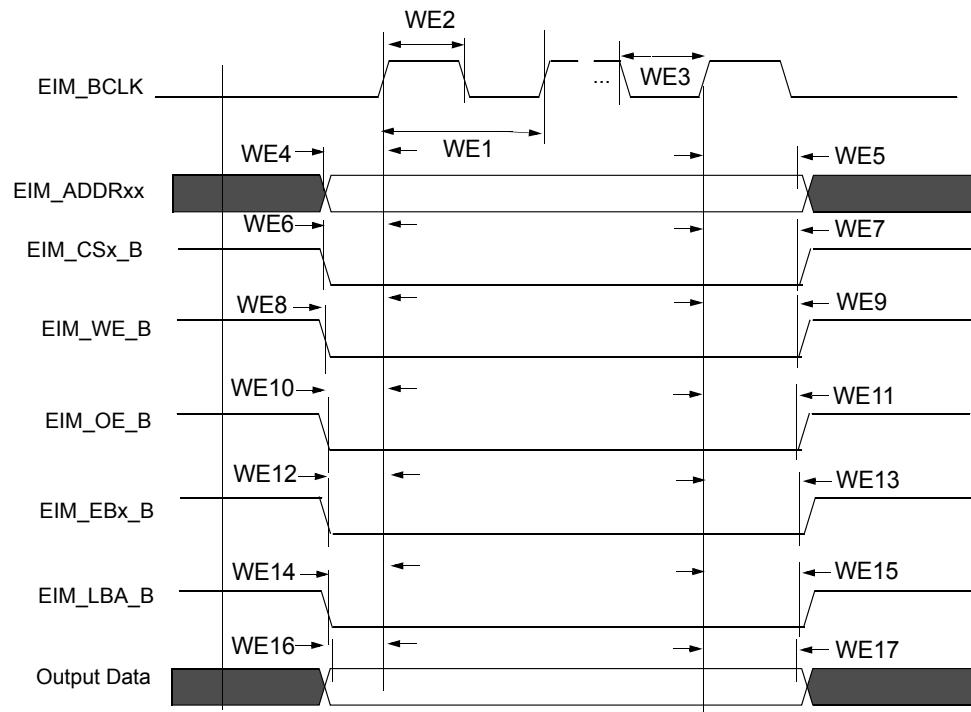


Figure 9. EIM Outputs Timing Diagram

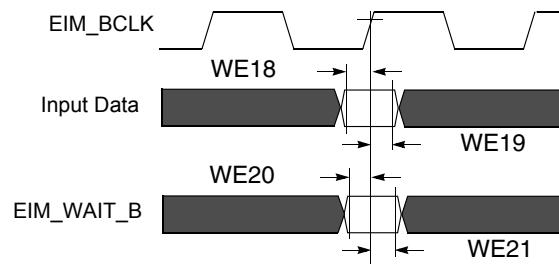


Figure 10. EIM Inputs Timing Diagram

4.9.3.3 Examples of EIM Synchronous Accesses

Table 39. EIM Bus Timing Parameters¹

ID	Parameter	BCD = 0		BCD = 1		BCD = 2		BCD = 3	
		Min	Max	Min	Max	Min	Max	Min	Max
WE1	EIM_BCLK Cycle time ²	t	—	2 x t	—	3 x t	—	4 x t	—
WE2	EIM_BCLK Low Level Width	0.4 x t	—	0.8 x t	—	1.2 x t	—	1.6 x t	—
WE3	EIM_BCLK High Level Width	0.4 x t	—	0.8 x t	—	1.2 x t	—	1.6 x t	—

Table 39. EIM Bus Timing Parameters (continued)¹

ID	Parameter	BCD = 0		BCD = 1		BCD = 2		BCD = 3	
		Min	Max	Min	Max	Min	Max	Min	Max
WE4	Clock rise to address valid ³	-0.5 x t - 1.25	-0.5 x t + 1.75	-t - 1.25	-t + 1.75	-1.5 x t - 1.25	-1.5 x t + 1.75	-2 x t - 1.25	-2 x t + 1.75
WE5	Clock rise to address invalid	0.5 x t - 1.25	0.5 x t + 1.75	t - 1.25	t + 1.75	1.5 x t - 1.25	1.5 x t + 1.75	2 x t - 1.25	2 x t + 1.75
WE6	Clock rise to EIM_CSx_B valid	-0.5 x t - 1.25	-0.5 x t + 1.75	-t - 1.25	-t + 1.75	-1.5 x t - 1.25	-1.5 x t + 1.75	-2 x t - 1.25	-2 x t + 1.75
WE7	Clock rise to EIM_CSx_B invalid	0.5 x t - 1.25	0.5 x t + 1.75	t - 1.25	t + 1.75	1.5 x t - 1.25	1.5 x t + 1.75	2 x t - 1.25	2 x t + 1.75
WE8	Clock rise to EIM_WE_B Valid	-0.5 x t - 1.25	-0.5 x t + 1.75	-t - 1.25	-t + 1.75	-1.5 x t - 1.25	-1.5 x t + 1.75	-2 x t - 1.25	-2 x t + 1.75
WE9	Clock rise to EIM_WE_B Invalid	0.5 x t - 1.25	0.5 x t + 1.75	t - 1.25	t + 1.75	1.5 x t - 1.25	1.5 x t + 1.75	2 x t - 1.25	2 x t + 1.75
WE10	Clock rise to EIM_OE_B Valid	-0.5 x t - 1.25	-0.5 x t + 1.75	-t - 1.25	-t + 1.75	-1.5 x t - 1.25	-1.5 x t + 1.75	-2 x t - 1.25	-2 x t + 1.75
WE11	Clock rise to EIM_OE_B Invalid	0.5 x t - 1.25	0.5 x t + 1.75	t - 1.25	t + 1.75	1.5 x t - 1.25	1.5 x t + 1.75	2 x t - 1.25	2 x t + 1.75
WE12	Clock rise to EIM_EBx_B Valid	-0.5 x t - 1.25	-0.5 x t + 1.75	-t - 1.25	-t + 1.75	-1.5 x t - 1.25	-1.5 x t + 1.75	-2 x t - 1.25	-2 x t + 1.75
WE13	Clock rise to EIM_EBx_B Invalid	0.5 x t - 1.25	0.5 x t + 1.75	t - 1.25	t + 1.75	1.5 x t - 1.25	1.5 x t + 1.75	2 x t - 1.25	2 x t + 1.75
WE14	Clock rise to EIM_LBA_B Valid	-0.5 x t - 1.25	-0.5 x t + 1.75	-t - 1.25	-t + 1.75	-1.5 x t - 1.25	-1.5 x t + 1.75	-2 x t - 1.25	-2 x t + 1.75
WE15	Clock rise to EIM_LBA_B Invalid	0.5 x t - 1.25	0.5 x t + 1.75	t - 1.25	t + 1.75	1.5 x t - 1.25	1.5 x t + 1.75	2 x t - 1.25	2 x t + 1.75
WE16	Clock rise to Output Data Valid	-0.5 x t - 1.25	-0.5 x t + 1.75	-t - 1.25	-t + 1.75	-1.5 x t - 1.25	-1.5 x t + 1.75	-2 x t - 1.25	-2 x t + 1.75
WE17	Clock rise to Output Data Invalid	0.5 x t - 1.25	0.5 x t + 1.75	t - 1.25	t + 1.75	1.5 x t - 1.25	1.5 x t + 1.75	2 x t - 1.25	2 x t + 1.75
WE18	Input Data setup time to Clock rise	2	—	4	—	—	—	—	—
WE19	Input Data hold time from Clock rise	2	—	2	—	—	—	—	—
WE20	EIM_WAIT_B setup time to Clock rise	2	—	4	—	—	—	—	—
WE21	EIM_WAIT_B hold time from Clock rise	2	—	2	—	—	—	—	—

Electrical Characteristics

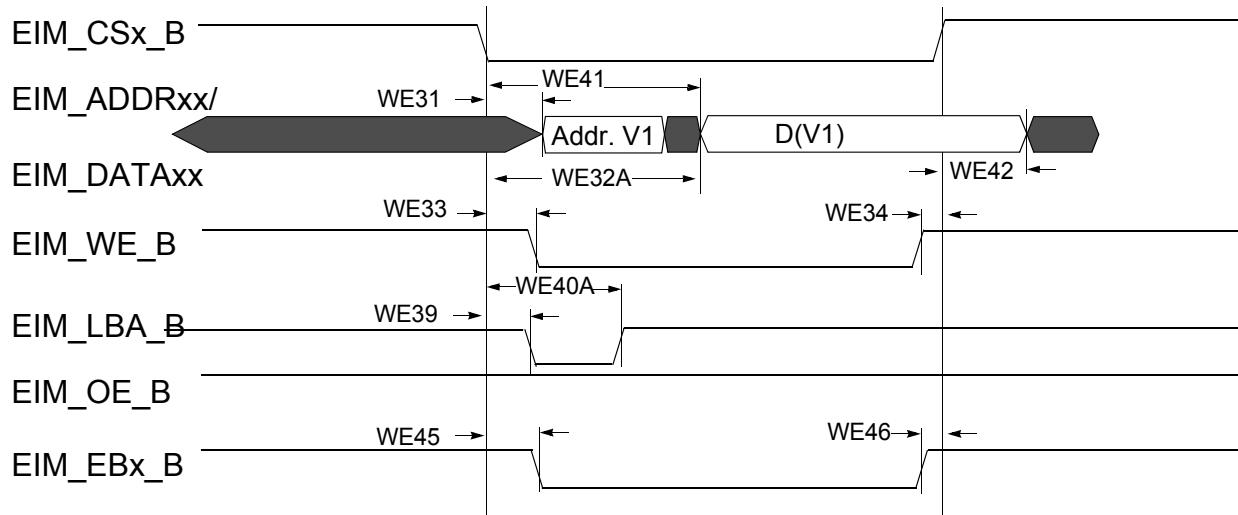


Figure 18. Asynchronous A/D Muxed Write Access

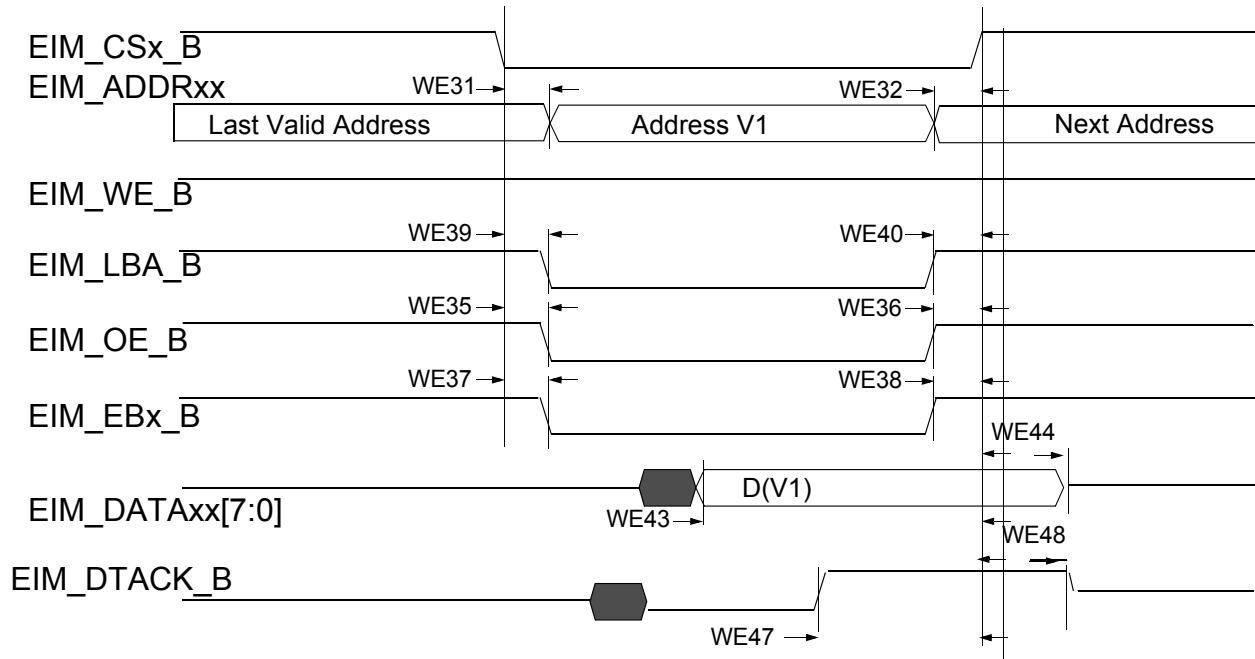


Figure 19. DTACK Mode Read Access (DAP=0)

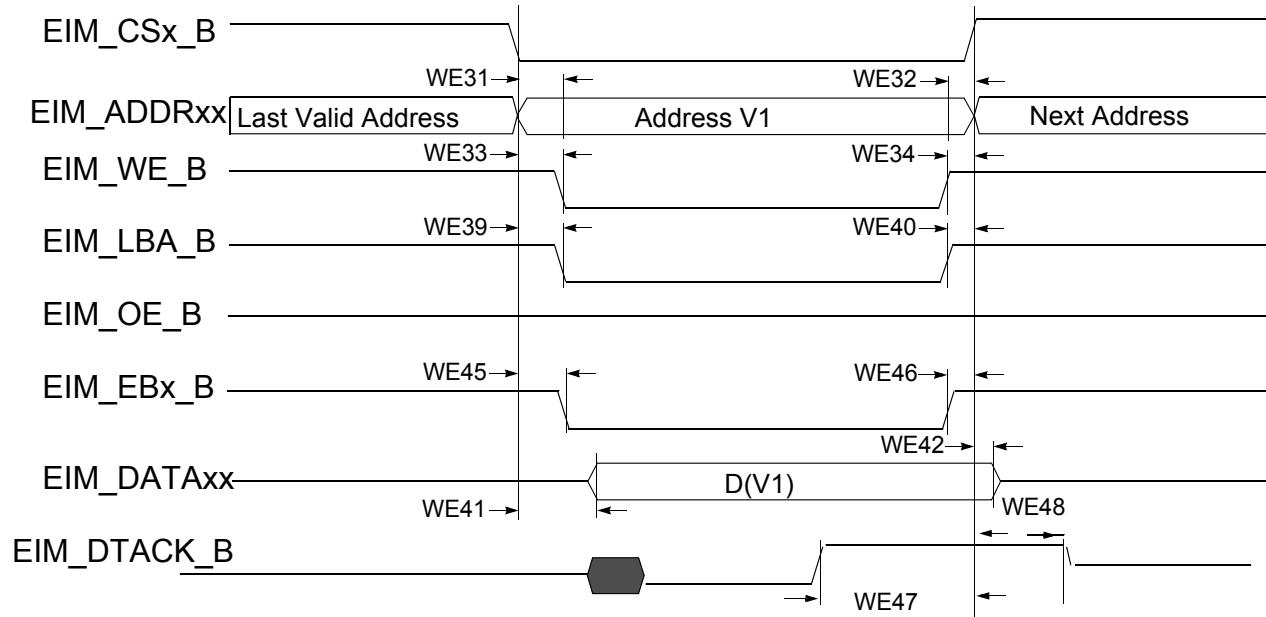


Figure 20. DTACK Mode Write Access (DAP=0)

Table 40. EIM Asynchronous Timing Parameters Table Relative Chip to Select

Ref No.	Parameter	Determination by Synchronous measured parameters ¹	Min	Max (If 132 MHz is supported by SoC)	Unit
WE31	EIM_CSx_B valid to Address Valid	WE4 - WE6 - CSA ²	—	3 - CSA	ns
WE32	Address Invalid to EIM_CSx_B invalid	WE7 - WE5 - CSN ³	—	3 - CSN	ns
WE32A(muxed A/D)	EIM_CSx_B valid to Address Invalid	$t^4 + WE4 - WE7 + (ADVN^5 + ADVA^6 + 1 - CSA)$	$-3 + (ADVN + ADVA + 1 - CSA)$	—	ns
WE33	EIM_CSx_B Valid to EIM_WE_B Valid	WE8 - WE6 + (WEA - WCSA)	—	3 + (WEA - WCSA)	ns
WE34	EIM_WE_B Invalid to EIM_CSx_B Invalid	WE7 - WE9 + (WEN - WCSN)	—	3 - (WEN_WCSN)	ns
WE35	EIM_CSx_B Valid to EIM_OE_B Valid	WE10 - WE6 + (OEA - RCSA)	—	3 + (OEA - RCSA)	ns
WE35A (muxed A/D)	EIM_CSx_B Valid to EIM_OE_B Valid	WE10 - WE6 + (OEA + RADVN + RADVA + ADH + 1 - RCSA)	$-3 + (OEA + RADVN+RADVA+ADH+1-RCSA)$	$3 + (OEA + RADVN+RADVA+ADH+1-RCSA)$	ns
WE36	EIM_OE_B Invalid to EIM_CSx_B Invalid	WE7 - WE11 + (OEN - RCSN)	—	3 - (OEN - RCSN)	ns
WE37	EIM_CSx_B Valid to EIM_EBx_B Valid (Read access)	WE12 - WE6 + (RBEA - RCSA)	—	3 + (RBEA - RCSA)	ns

- ² bl = bit length
wl = word length
wr = word length relative
- ³ ESAI_TX_CLK(SCKT pin) = transmit clock
ESAI_RX_CLK(SCKR pin) = receive clock
ESAI_TX_FS(FST pin) = transmit frame sync
ESAI_RX_FS(FSR pin) = receive frame sync
ESAI_TX_HF_CLK(HCKT pin) = transmit high frequency clock
ESAI_RX_HF_CLK(HCKR pin) = receive high frequency clock
- ⁴ For the internal clock, the external clock cycle is defined by Icyc and the ESAI control register.
- ⁵ The word-relative frame sync signal waveform relative to the clock operates in the same manner as the bit-length frame sync signal waveform, but it spreads from one serial clock before the first bit clock (like the bit length frame sync signal), until the second-to-last bit clock of the first word in the frame.
- ⁶ Periodically sampled and not 100% tested.

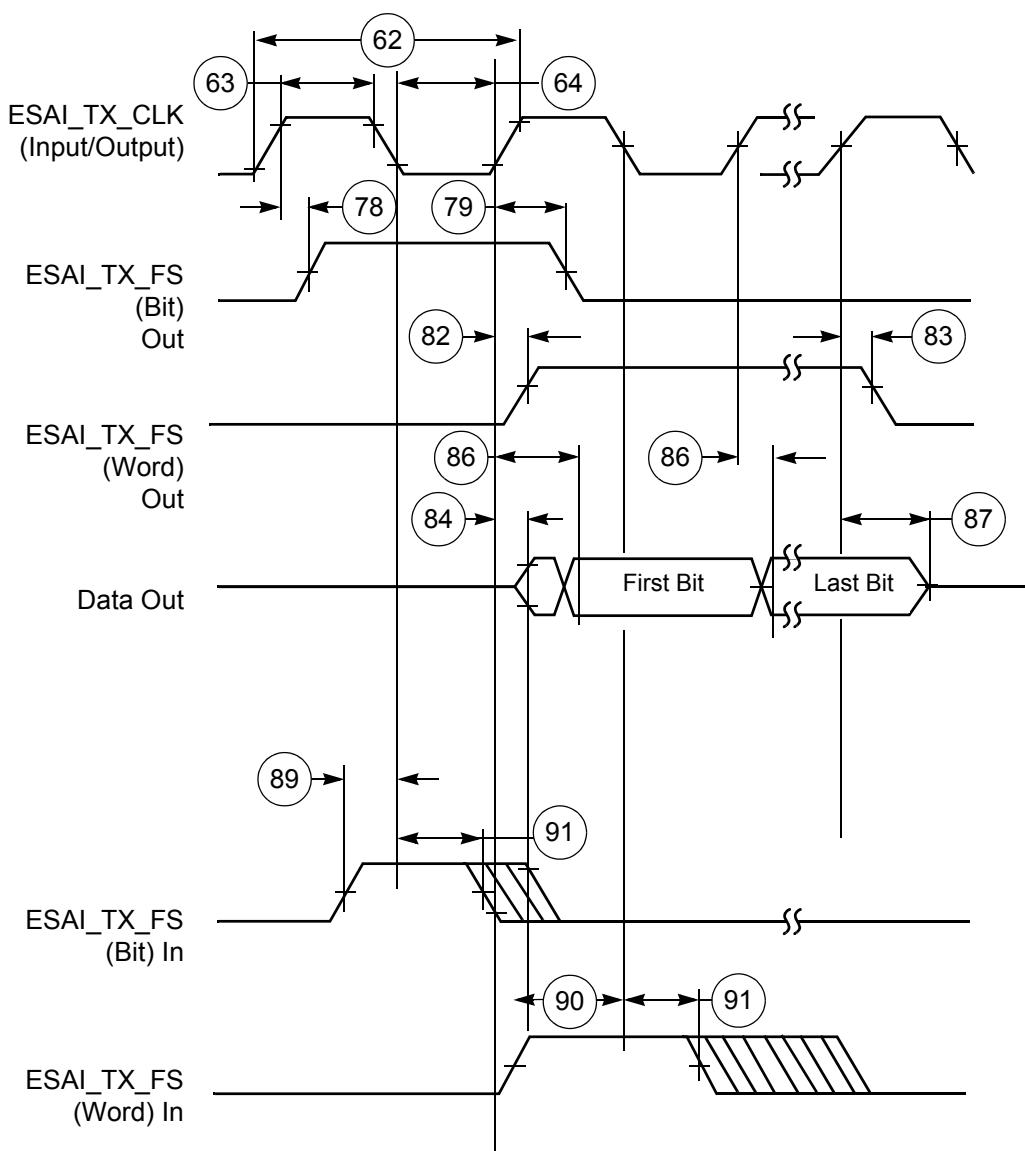


Figure 37. ESAI Transmitter Timing

Electrical Characteristics

Figure 45 shows MII transmit signal timings. Table 55 describes the timing parameters (M5–M8) shown in the figure.

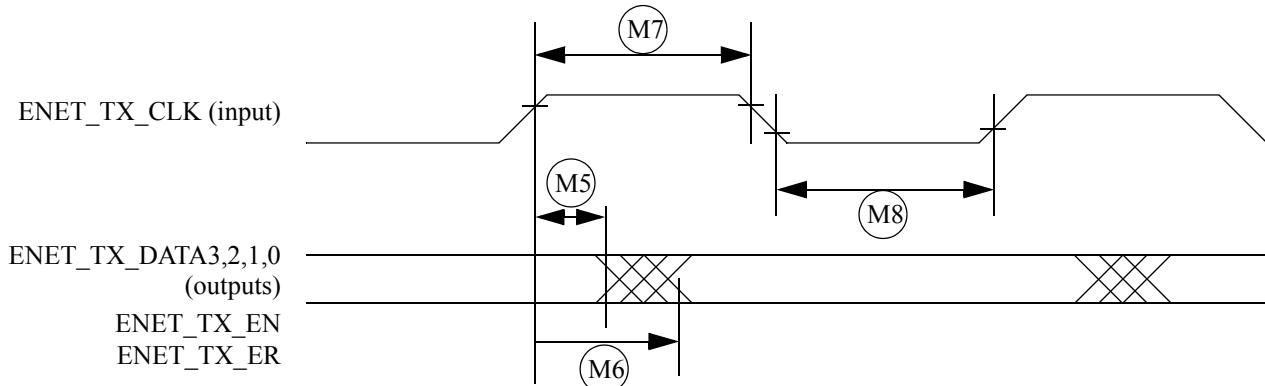


Figure 45. MII Transmit Signal Timing Diagram

Table 55. MII Transmit Signal Timing

ID	Characteristic ¹	Min.	Max.	Unit
M5	ENET_TX_CLK to ENET_TX_DATA3,2,1,0, ENET_TX_EN, ENET_TX_ER invalid	5	—	ns
M6	ENET_TX_CLK to ENET_TX_DATA3,2,1,0, ENET_TX_EN, ENET_TX_ER valid	—	20	ns
M7	ENET_TX_CLK pulse width high	35%	65%	ENET_TX_CLK period
M8	ENET_TX_CLK pulse width low	35%	65%	ENET_TX_CLK period

¹ ENET_TX_EN, ENET_TX_CLK, and ENET0_RXD0 have the same timing in 10-Mbps 7-wire interface mode.

4.12.5.1.3 MII Asynchronous Inputs Signal Timing (ENET_CRS and ENET_COL)

Figure 46 shows MII asynchronous input timings. Table 56 describes the timing parameter (M9) shown in the figure.

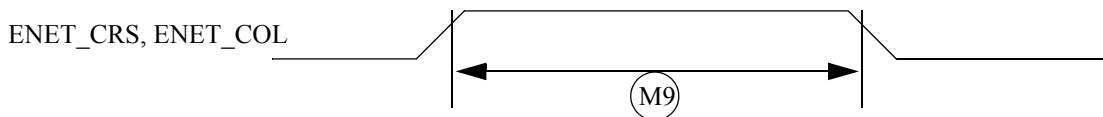


Figure 46. MII Async Inputs Timing Diagram

Table 56. MII Asynchronous Inputs Signal Timing

ID	Characteristic	Min.	Max.	Unit
M9 ¹	ENET_CRS to ENET_COL minimum pulse width	1.5	—	ENET_TX_CLK period

¹ ENET_COL has the same timing in 10-Mbit 7-wire interface mode.

Electrical Characteristics

Figure 48 shows RMII mode timings. Table 58 describes the timing parameters (M16–M21) shown in the figure.

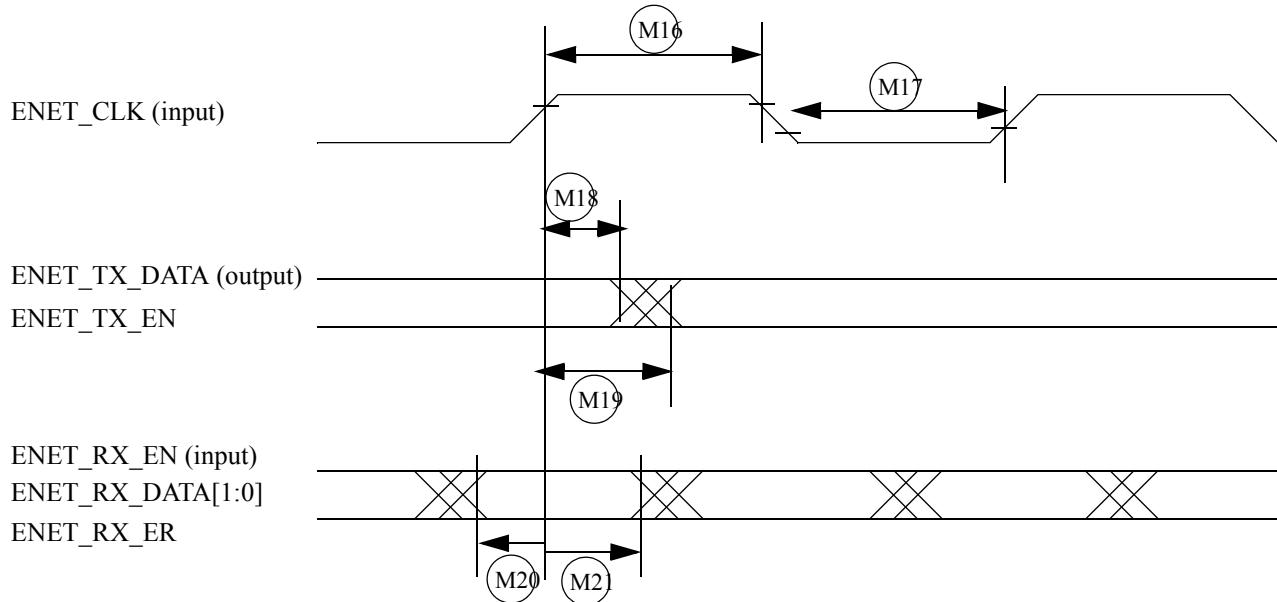


Figure 48. RMII Mode Signal Timing Diagram

Table 58. RMII Signal Timing

ID	Characteristic	Min.	Max.	Unit
M16	ENET_CLK pulse width high	35%	65%	ENET_CLK period
M17	ENET_CLK pulse width low	35%	65%	ENET_CLK period
M18	ENET_CLK to ENET0_TXD[1:0], ENET_TX_DATA invalid	4	—	ns
M19	ENET_CLK to ENET0_TXD[1:0], ENET_TX_DATA valid	—	13	ns
M20	ENET_RX_DATAD[1:0], ENET_RX_EN(ENET_RX_EN), ENET_RX_ER to ENET_CLK setup	2	—	ns
M21	ENET_CLK to ENET_RX_DATAD[1:0], ENET_RX_EN, ENET_RX_ER hold	2	—	ns

4.12.6 Flexible Controller Area Network (FLEXCAN) AC Electrical Specifications

The Flexible Controller Area Network (FlexCAN) module is a communication controller implementing the CAN protocol according to the CAN 2.0B protocol specification. The processor has two CAN modules available for systems design. Tx and Rx ports for both modules are multiplexed with other I/O pins. See the IOMUXC chapter of the *i.MX 6ULL Reference Manual* (IMX6ULLRM) to see which pins expose Tx and Rx pins; these ports are named FLEXCAN_TX and FLEXCAN_RX, respectively.

Electrical Characteristics

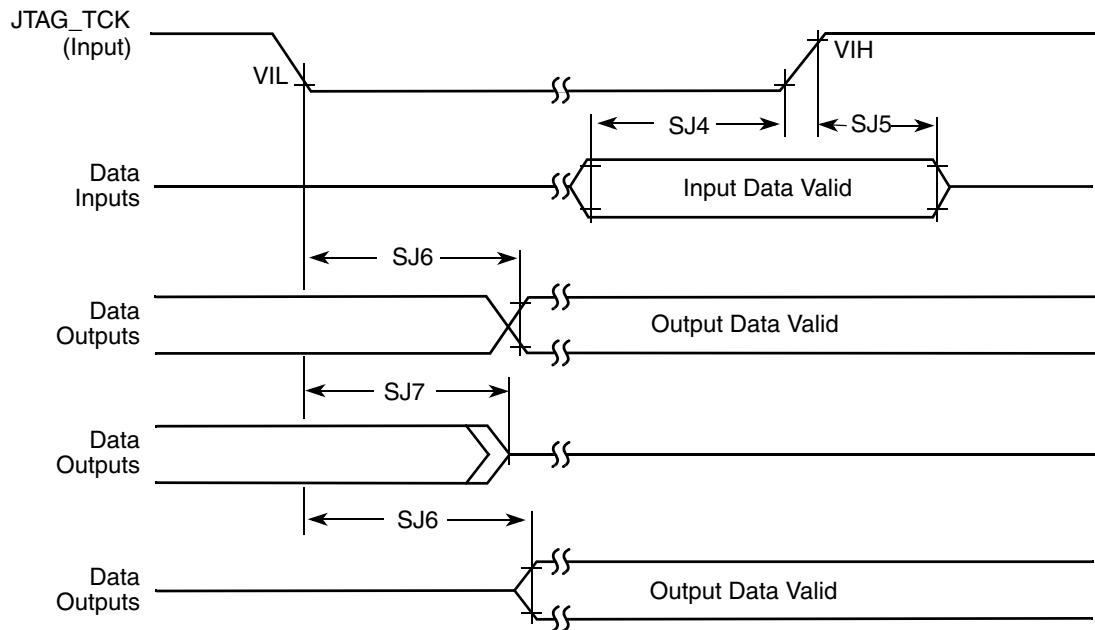


Figure 60. Boundary Scan (JTAG) Timing Diagram

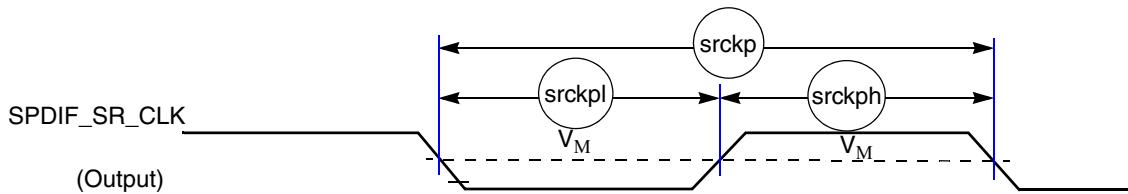


Figure 63. SPDIF_SR_CLK Timing Diagram

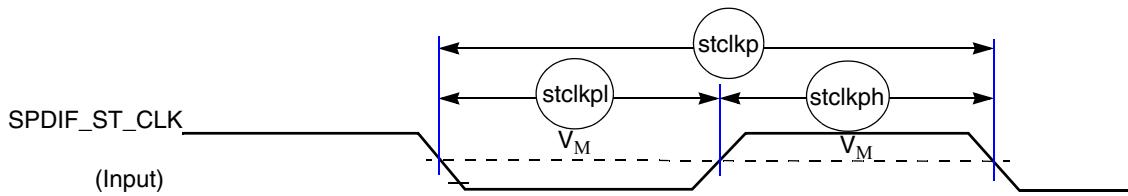


Figure 64. SPDIF_ST_CLK Timing Diagram

4.12.14 UART I/O Configuration and Timing Parameters

4.12.14.1 UART RS-232 Serial Mode Timing

The following sections describe the electrical information of the UART module in the RS-232 mode.

4.12.14.1.1 UART Transmitter

Figure 65 depicts the transmit timing of UART in the RS-232 serial mode, with 8 data bit/1 stop bit format. Table 72 lists the UART RS-232 serial mode transmits timing characteristics.

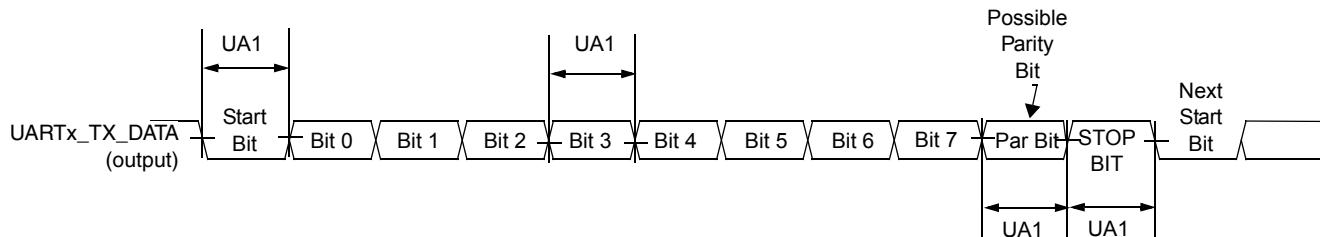


Figure 65. UART RS-232 Serial Mode Transmit Timing Diagram

Table 72. RS-232 Serial Mode Transmit Timing Parameters

ID	Parameter	Symbol	Min	Max	Unit
UA1	Transmit Bit Time	t_{Tbit}	$1/F_{baud_rate}^1 - T_{ref_clk}^2$	$1/F_{baud_rate} + T_{ref_clk}$	—

¹ F_{baud_rate} : Baud rate frequency. The maximum baud rate the UART can support is (ipg_perclk frequency)/16.

² T_{ref_clk} : The period of UART reference clock ref_clk (ipg_perclk after RFDIV divider).

¹ F_{baud_rate} : Baud rate frequency. The maximum baud rate the UART can support is (ipg_perclk frequency)/16.

² T_{ref_clk} : The period of UART reference clock ref_clk (ipg_perclk after RFDIV divider).

UART IrDA Mode Receiver

Figure 68 depicts the UART IrDA mode receive timing, with 8 data bit/1 stop bit format. Table 75 lists the receive timing characteristics.

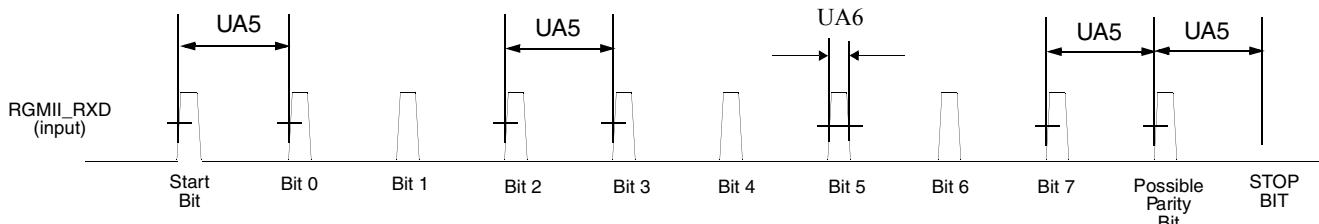


Figure 68. UART IrDA Mode Receive Timing Diagram

Table 75. IrDA Mode Receive Timing Parameters

ID	Parameter	Symbol	Min	Max	Unit
UA5	Receive Bit Time ¹ in IrDA mode	t_{RIRbit}	$1/F_{baud_rate}^2 - 1/(16 \times F_{baud_rate})$	$1/F_{baud_rate} + 1/(16 \times F_{baud_rate})$	—
UA6	Receive IR Pulse Duration	$t_{RIRpulse}$	1.41 μ s	$(5/16) \times (1/F_{baud_rate})$	—

¹ The UART receiver can tolerate $1/(16 \times F_{baud_rate})$ tolerance in each bit. But accumulation tolerance in one frame must not exceed $3/(16 \times F_{baud_rate})$.

² F_{baud_rate} : Baud rate frequency. The maximum baud rate the UART can support is (ipg_perclk frequency)/16.

4.12.15 USB PHY Parameters

This section describes the USB-OTG PHY parameters.

The USB PHY meets the electrical compliance requirements defined in the Universal Serial Bus Revision 2.0 OTG with the following amendments.

- USB ENGINEERING CHANGE NOTICE
 - Title: 5V Short Circuit Withstand Requirement Change
 - Applies to: Universal Serial Bus Specification, Revision 2.0
- Errata for USB Revision 2.0 April 27, 2000 as of 12/7/2000
- USB ENGINEERING CHANGE NOTICE
 - Title: Pull-up/Pull-down resistors
 - Applies to: Universal Serial Bus Specification, Revision 2.0
- USB ENGINEERING CHANGE NOTICE
 - Title: Suspend Current Limit Changes
 - Applies to: Universal Serial Bus Specification, Revision 2.0

Electrical Characteristics

4.13.1.1.1 12-bit ADC characteristics

Table 77. 12-bit ADC Characteristics ($V_{REFH} = V_{DDAD}$, $V_{REFL} = V_{SSAD}$)

Characteristic	Conditions ¹	Symb	Min	Typ ²	Max	Unit	Comment
[L:] Supply Current	ADLPC=1, ADHSC=0	I_{DDAD}	—	250	—	μA	ADLSMP=0 ADSTS=10 ADCO=1
	ADLPC=0, ADHSC=0			350			
	ADLPC=0, ADHSC=1			400			
[L:] Supply Current	Stop, Reset, Module Off	I_{DDAD}	—	0.01	0.8	μA	—
ADC Asynchronous Clock Source	ADHSC=0	f_{ADACK}	—	10	—	MHz	$t_{ADACK} = 1/f_{ADACK}$
	ADHSC=1		—	20			
Sample Cycles	ADLSMP=0, ADSTS=00	Csamp	—	2	—	cycles	—
	ADLSMP=0, ADSTS=01			4			
	ADLSMP=0, ADSTS=10			6			
	ADLSMP=0, ADSTS=11			8			
	ADLSMP=1, ADSTS=00			12			
	ADLSMP=1, ADSTS=01			16			
	ADLSMP=1, ADSTS=10			20			
	ADLSMP=1, ADSTS=11			24			

Boot Mode Configuration

Table 86. SD/MMC Boot through USDH2

Ball Name	Signal Name	Mux Mode	Common	4-bit	8-bit	BOOT_CFG1[1]=1 (SD Power Cycle)
NAND_RE_B	usdhc2.CLK	Alt 1	Yes			
NAND_WE_B	usdhc2.CMD	Alt 1	Yes			
NAND_DATA00	usdhc2.DATA0	Alt 1	Yes			
NAND_DATA01	usdhc2.DATA1	Alt 1		Yes	Yes	
NAND_DATA02	usdhc2.DATA2	Alt 1		Yes	Yes	
NAND_DATA03	usdhc2.DATA3	Alt 1	Yes			
NAND_DATA04	usdhc2.DATA4	Alt 1			Yes	
NAND_DATA05	usdhc2.DATA5	Alt 1			Yes	
NAND_DATA06	usdhc2.DATA6	Alt 1			Yes	
NAND_DATA07	usdhc2.DATA7	Alt 1			Yes	
NAND_ALE	NAND_ALE ¹	Alt 5				Yes
GPIO1_IO08	usdhc2.VSELECT	Alt 4				Yes

¹ The Boot ROM uses NAND_ALE to implement SD2_RESET_B.

Table 87. NOR/OneNAND Boot through EIM

Ball Name	Signal Name	Mux Mode	Common	ADL16 Non-Mux	AD16 Mux
CSI_DATA00	weim.AD[0]	Alt 4	Yes		
CSI_DATA01	weim.AD[1]	Alt 4	Yes		
CSI_DATA02	weim.AD[2]	Alt 4	Yes		
CSI_DATA03	weim.AD[3]	Alt 4	Yes		
CSI_DATA04	weim.AD[4]	Alt 4	Yes		
CSI_DATA05	weim.AD[5]	Alt 4	Yes		
CSI_DATA06	weim.AD[6]	Alt 4	Yes		
CSI_DATA07	weim.AD[7]	Alt 4	Yes		
NAND_DATA00	weim.AD[8]	Alt 4	Yes		
NAND_DATA01	weim.AD[9]	Alt 4	Yes		
NAND_DATA02	weim.AD[10]	Alt 4	Yes		
NAND_DATA03	weim.AD[11]	Alt 4	Yes		
NAND_DATA04	weim.AD[12]	Alt 4	Yes		
NAND_DATA05	weim.AD[13]	Alt 4	Yes		
NAND_DATA06	weim.AD[14]	Alt 4	Yes		

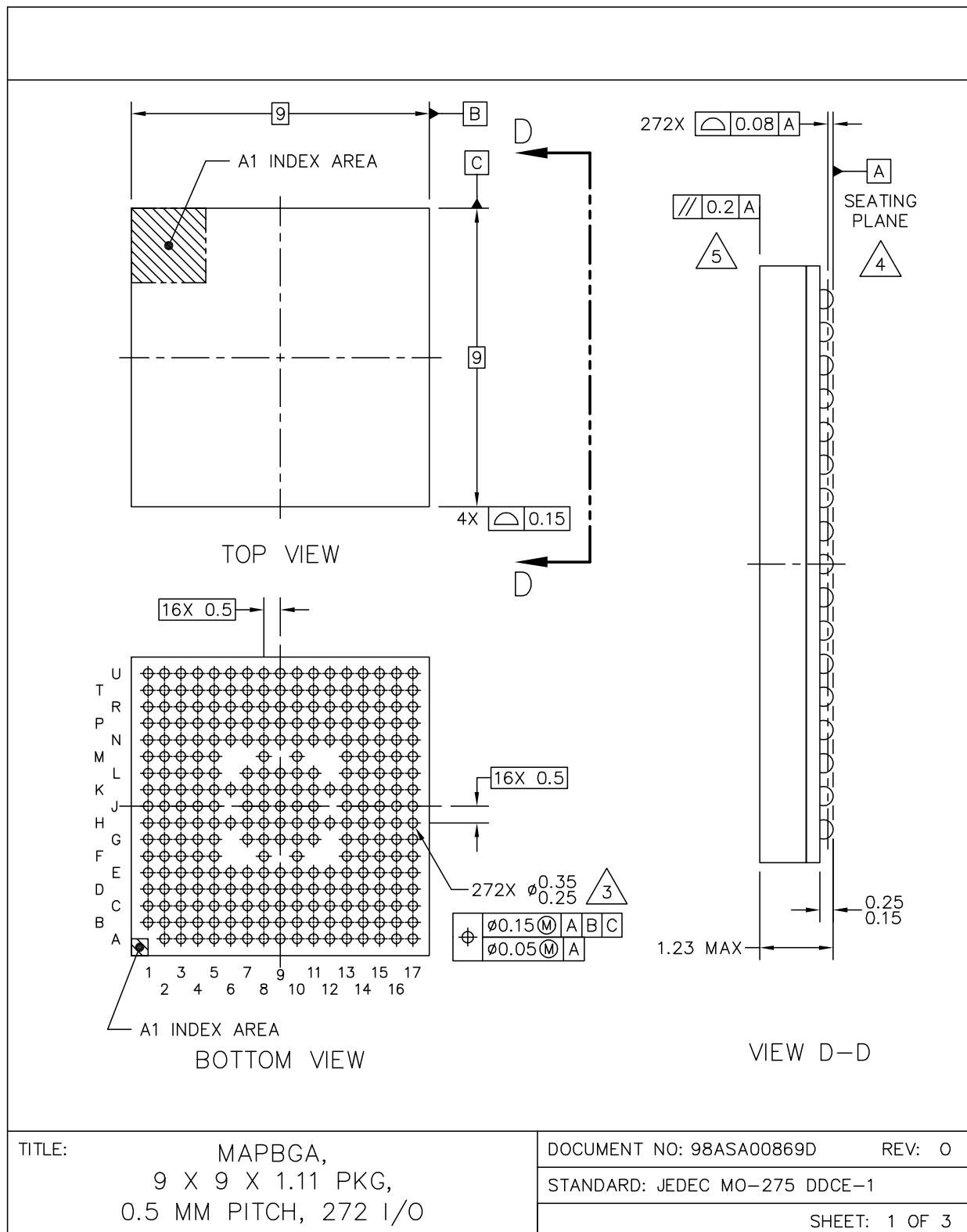


Figure 71. 9 x 9 mm BGA, Case x Package Top, Bottom, and Side Views

Table 94 shows an alpha-sorted list of functional contact assignments for the 9 x 9 mm package.

Table 94. 9 x 9 mm Functional Contact Assignments

Ball Name	9x9 Ball	Power Group	Ball Type	Out of Reset Condition			
				Default Mode	Default Function	Input/Output	Value
BOOT_MODE0	T8	VDD_SNVS_IN	GPIO	ALT5	GPIO5_IO10	Input	100 kΩ pull-down
BOOT_MODE1	U8	VDD_SNVS_IN	GPIO	ALT5	GPIO5_IO11	Input	100 kΩ pull-down
CCM_CLK1_N	U16	VDD_HIGH_CAP	LVDS	—	CCM_CLK1_N	—	—
CCM_CLK1_P	T16	VDD_HIGH_CAP	LVDS	—	CCM_CLK1_P	—	—
CCM_PMIC_STBY_REQ	U7	VDD_SNVS_IN	GPIO	ALT0	CCM_PMIC_VSTBY_REQ	Output	—
CSI_DATA00	C3	NVCC_CSI	GPIO	ALT5	GPIO4_IO21	Input	Keeper
CSI_DATA01	D4	NVCC_CSI	GPIO	ALT5	GPIO4_IO22	Input	Keeper
CSI_DATA02	B2	NVCC_CSI	GPIO	ALT5	GPIO4_IO23	Input	Keeper
CSI_DATA03	D1	NVCC_CSI	GPIO	ALT5	GPIO4_IO24	Input	Keeper
CSI_DATA04	C4	NVCC_CSI	GPIO	ALT5	GPIO4_IO25	Input	Keeper
CSI_DATA05	B3	NVCC_CSI	GPIO	ALT5	GPIO4_IO26	Input	Keeper
CSI_DATA06	A3	NVCC_CSI	GPIO	ALT5	GPIO4_IO27	Input	Keeper
CSI_DATA07	C2	NVCC_CSI	GPIO	ALT5	GPIO4_IO28	Input	Keeper
CSI_HSYNC	D2	NVCC_CSI	GPIO	ALT5	GPIO4_IO20	Input	Keeper
CSI_MCLK	C1	NVCC_CSI	GPIO	ALT5	GPIO4_IO17	Input	Keeper
CSI_PIXCLK	D5	NVCC_CSI	GPIO	ALT5	GPIO4_IO18	Input	Keeper
CSI_VSYNC	D3	NVCC_CSI	GPIO	ALT5	GPIO4_IO19	Input	Keeper
DRAM_ADDR00	G1	NVCC_DRAM	DDR	ALT0	DRAM_ADDR00	Output	100 kΩ pull-up
DRAM_ADDR01	G2	NVCC_DRAM	DDR	ALT0	DRAM_ADDR01	Output	100 kΩ pull-up
DRAM_ADDR02	H1	NVCC_DRAM	DDR	ALT0	DRAM_ADDR02	Output	100 kΩ pull-up
DRAM_ADDR03	J2	NVCC_DRAM	DDR	ALT0	DRAM_ADDR03	Output	100 kΩ pull-up
DRAM_ADDR04	M4	NVCC_DRAM	DDR	ALT0	DRAM_ADDR04	Output	100 kΩ pull-up
DRAM_ADDR05	H2	NVCC_DRAM	DDR	ALT0	DRAM_ADDR05	Output	100 kΩ pull-up
DRAM_ADDR06	E4	NVCC_DRAM	DDR	ALT0	DRAM_ADDR06	Output	100 kΩ pull-up

Table 94. 9 x 9 mm Functional Contact Assignments (continued)

DRAM_DATA09	U2	NVCC_DRAM	DDR	ALT0	DRAM_DATA09	Input	100 kΩ pull-up
DRAM_DATA10	P3	NVCC_DRAM	DDR	ALT0	DRAM_DATA10	Input	100 kΩ pull-up
DRAM_DATA11	R2	NVCC_DRAM	DDR	ALT0	DRAM_DATA11	Input	100 kΩ pull-up
DRAM_DATA12	P4	NVCC_DRAM	DDR	ALT0	DRAM_DATA12	Input	100 kΩ pull-up
DRAM_DATA13	N2	NVCC_DRAM	DDR	ALT0	DRAM_DATA13	Input	100 kΩ pull-up
DRAM_DATA14	N1	NVCC_DRAM	DDR	ALT0	DRAM_DATA14	Input	100 kΩ pull-up
DRAM_DATA15	P2	NVCC_DRAM	DDR	ALT0	DRAM_DATA15	Input	100 kΩ pull-up
DRAM_DQM0	U4	NVCC_DRAM	DDR	ALT0	DRAM_DQM0	Output	100 kΩ pull-up
DRAM_DQM1	R1	NVCC_DRAM	DDR	ALT0	DRAM_DQM1	Output	100 kΩ pull-up
DRAM_ODT0	K2	NVCC_DRAM	DDR	ALT0	DRAM_ODT0	Output	100 kΩ pull-down
DRAM_ODT1	E1	NVCC_DRAM	DDR	ALT0	DRAM_ODT1	Output	100 kΩ pull-down
DRAM_RAS_B	L4	NVCC_DRAM	DDR	ALT0	DRAM_RAS_B	Output	100 kΩ pull-up
DRAM_RESET	F2	NVCC_DRAM	DDR	ALT0	DRAM_RESET	Output	100 kΩ pull-down
DRAM_SDBA0	H3	NVCC_DRAM	DDR	ALT0	DRAM_SDBA0	Output	100 kΩ pull-up
DRAM_SDBA1	F5	NVCC_DRAM	DDR	ALT0	DRAM_SDBA1	Output	100 kΩ pull-up
DRAM_SDBA2	G3	NVCC_DRAM	DDR	ALT0	DRAM_SDBA2	Output	100 kΩ pull-up
DRAM_SDCKE0	L2	NVCC_DRAM	DDR	ALT0	DRAM_SDCKE0	Output	100 kΩ pull-down
DRAM_SDCKE1	K1	NVCC_DRAM	DDR	ALT0	DRAM_SDCKE1	Output	100 kΩ pull-down
DRAM_SDCLK0_N	K4	NVCC_DRAM	DDRC_LK	ALT0	DRAM_SDCLK0_N	Input	100 kΩ pull-up
DRAM_SDCLK0_P	K3	NVCC_DRAM	DDRC_LK	ALT0	DRAM_SDCLK0_P	Input	100 kΩ pull-up
DRAM_SDQS0_N	R5	NVCC_DRAM	DDRC_LK	ALT0	DRAM_SDQS0_N	Input	100 kΩ pull-down

Table 94. 9 x 9 mm Functional Contact Assignments (continued)

SNVS_PMIC_ON_REQ	T7	VDD_SNVS_IN	GPIO	ALT0	SNVS_PMIC_ON_REQ	Output	100 kΩ pull-up
SNVS_TAMPER0	R8	VDD_SNVS_IN	GPIO	ALT5	GPIO5_IO00/SNVS_TAMPE_R0 ¹	Input	Keeper ^{1,2}
SNVS_TAMPER1	P6	VDD_SNVS_IN	GPIO	ALT5	GPIO5_IO01/SNVS_TAMPE_R1 ¹	Input	Keeper/N or connected ^{1,2}
SNVS_TAMPER2	N10	VDD_SNVS_IN	GPIO	ALT5	GPIO5_IO02/SNVS_TAMPE_R2 ¹	Input	Keeper/N or connected ^{1,2}
SNVS_TAMPER3	P10	VDD_SNVS_IN	GPIO	ALT5	GPIO5_IO03/SNVS_TAMPE_R3 ¹	Input	Keeper/N or connected ^{1,2}
SNVS_TAMPER4	P7	VDD_SNVS_IN	GPIO	ALT5	GPIO5_IO04/SNVS_TAMPE_R4 ¹	Input	Keeper/N or connected ^{1,2}
SNVS_TAMPER5	P8	VDD_SNVS_IN	GPIO	ALT5	GPIO5_IO05/SNVS_TAMPE_R5 ¹	Input	Keeper/N or connected ^{1,2}
SNVS_TAMPER6	R7	VDD_SNVS_IN	GPIO	ALT5	GPIO5_IO06/SNVS_TAMPE_R6 ¹	Input	Keeper/N or connected ^{1,2}
SNVS_TAMPER7	N9	VDD_SNVS_IN	GPIO	ALT5	GPIO5_IO07/SNVS_TAMPE_R7 ¹	Input	Keeper/N or connected ^{1,2}
SNVS_TAMPER8	N8	VDD_SNVS_IN	GPIO	ALT5	GPIO5_IO08/SNVS_TAMPE_R8 ¹	Input	Keeper/N or connected ^{1,2}
SNVS_TAMPER9	P9	VDD_SNVS_IN	GPIO	ALT5	GPIO5_IO09/SNVS_TAMPE_R9 ¹	Input	Keeper/N or connected ^{1,2}
TEST_MODE	N7	VDD_SNVS_IN	TCU	ALT0	TCU_TEST_MODE	Input	Keeper
UART1_CTS_B	L14	NVCC_UART	GPIO	ALT5	GPIO1_IO18	Input	Keeper
UART1_RTS_B	K14	NVCC_UART	GPIO	ALT5	GPIO1_IO19	Input	Keeper
UART1_RX_DATA	L17	NVCC_UART	GPIO	ALT5	GPIO1_IO17	Input	Keeper
UART1_TX_DATA	L15	NVCC_UART	GPIO	ALT5	GPIO1_IO16	Input	Keeper